



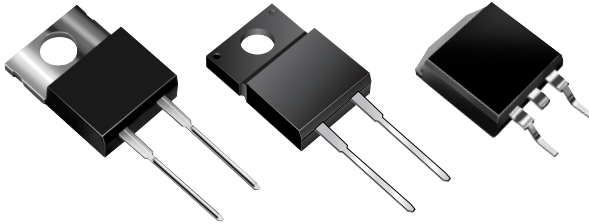
MBR10100, MBRF10100 & MBRB10100 Series

New Product

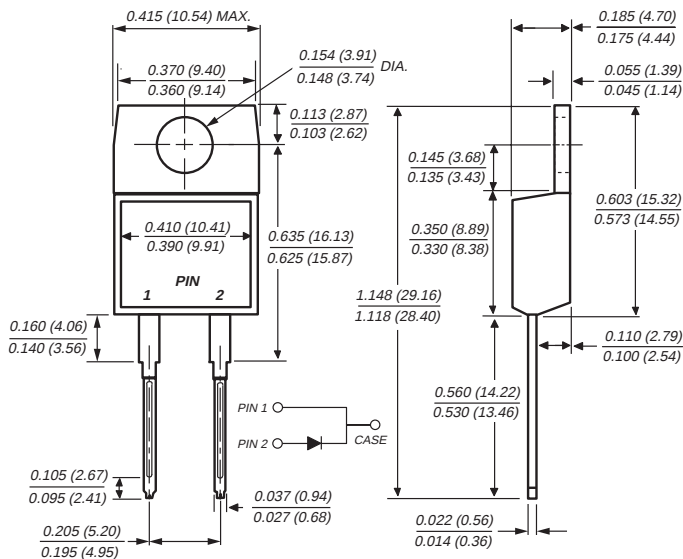
Vishay Semiconductors
formerly General Semiconductor

High Voltage Schottky Rectifiers

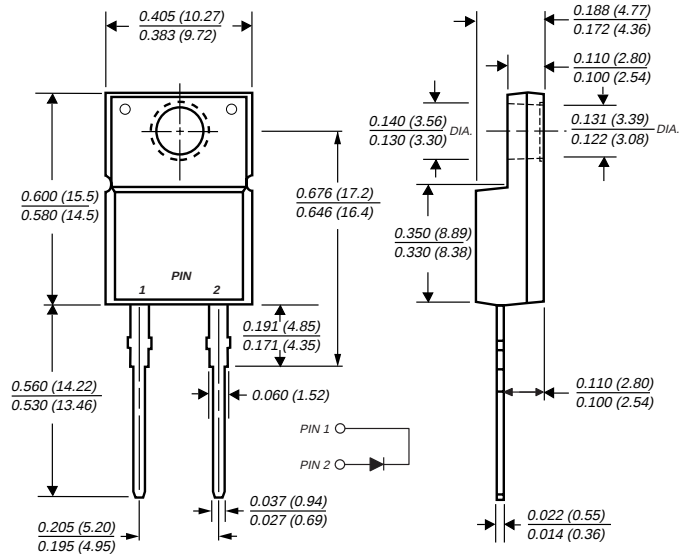
Reverse Voltage 90 to 100V
Forward Current 10A



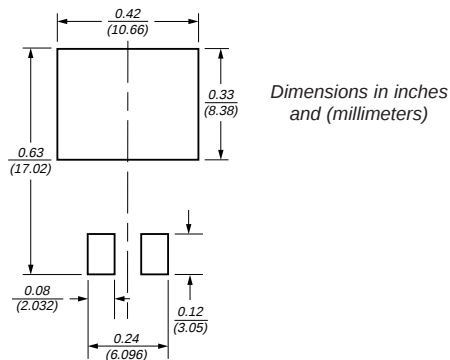
TO-220AC (MBR1090, MBR10100)



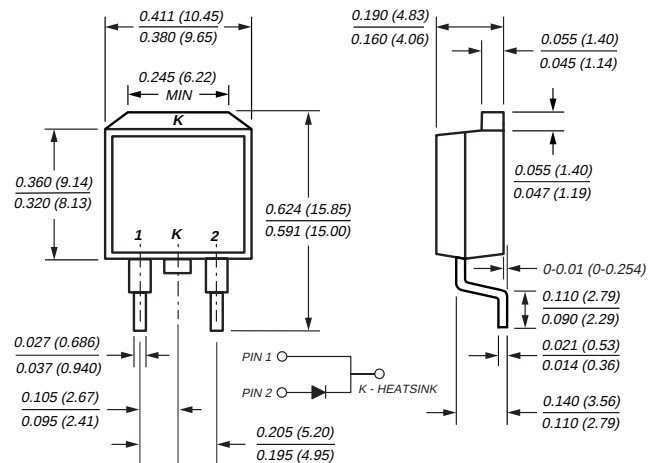
ITO-220AC (MBRF1090, MBRF10100)



Mounting Pad Layout TO-263AB



TO-263AB (MBRB1090, MBRB10100)



Features

- Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- Guardring for overvoltage protection
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 250°C/10 seconds, 0.25" (6.35mm) from case

Mechanical Data

Case: JEDEC TO-220AC, ITO-220AC & TO-263AB molded plastic body

Terminals: Plated leads, solderable per MIL-STD-750, Method 2026

Polarity: As marked

Mounting Position: Any

Mounting Torque: 10 in-lbs maximum

Weight: 0.08 oz., 2.24 g

MBR10100, MBRF10100 & MBRB10100 Series



Vishay Semiconductors
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Maximum Ratings (T_C = 25°C unless otherwise noted)

Parameter	Symbol	MBR1090	MBR10100	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	90	100	V
Working peak reverse voltage	V _{RWM}	90	100	V
Maximum DC blocking voltage	V _{DC}	90	100	V
Maximum average forward rectified current at T _C = 133°C	I _{F(AV)}	10		A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	150		A
Peak repetitive reverse current at t _p = 2μs, 1KHz	I _{RRM}	0.5		A
Voltage rate of change (rated V _R)	dv/dt	10,000		V/μs
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +175		°C
RMS Isolation voltage (MBRF type only) from terminals to heatsink with t = 1 second, RH ≤ 30%	V _{ISOL}	4500 ⁽¹⁾ 3500 ⁽²⁾ 1500 ⁽³⁾		V

Electrical Characteristics (T_C = 25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Maximum instantaneous forward voltage at: ⁽⁴⁾ I _F = 10A, T _C = 25°C I _F = 10A, T _C = 125°C I _F = 20A, T _C = 25°C I _F = 20A, T _C = 125°C	V _F	0.80 0.65 0.95 0.75	V
Maximum reverse current at working peak reverse voltage ⁽⁴⁾ T _J = 25°C T _J = 100°C	I _R	100 6.0	μA mA

Thermal Characteristics (T_C = 25°C unless otherwise noted)

Parameter	Symbol	MBR	MBRF	MBRB	Unit
Typical thermal resistance	R _{θJA} R _{θJC}	60 2	— 3.5	60 2	°C/W

Notes:

- (1) Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset
- (2) Clip mounting (on case), where leads do overlap heatsink
- (3) Screw mounting with 4-40 screw, where washer diameter is ≤ 4.9 mm (0.19")
- (4) Pulse test: 300μs pulse width, 1% duty cycle

Ordering Information

Product	Case	Package Code	Package Option
MBR1090, MBR10100	TO-220AC	45	Anti-Static tube, 50/tube, 2K/carton
MBRF1090, MBRF10100	ITO-220AC	45	Anti-Static tube, 50/tube, 2K/carton
MBRB1090, MBRB10100	TO-263AB	31 45 81	13" reel, 800/reel, 4.8K/carton Anti-Static tube, 50/tube, 2K/carton Anti-Static 13" reel, 800/reel, 4.8K/carton



Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 - Forward Current Derating Curve

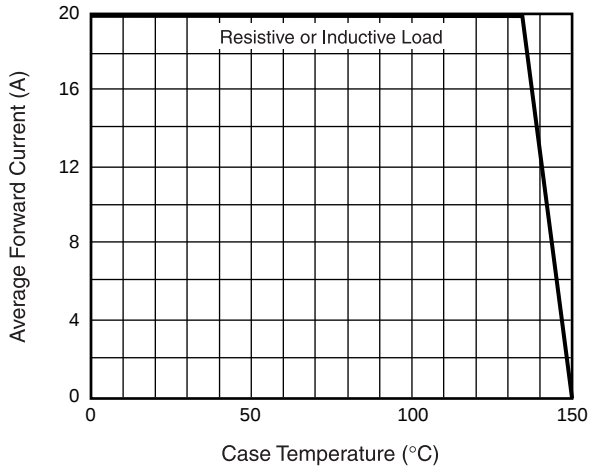


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

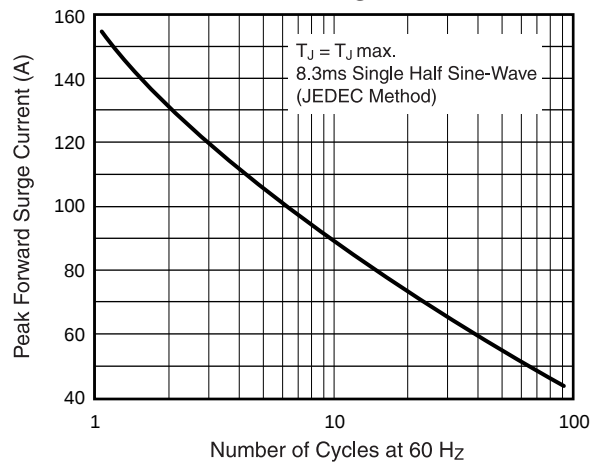


Fig. 3 - Typical Instantaneous Forward Characteristics

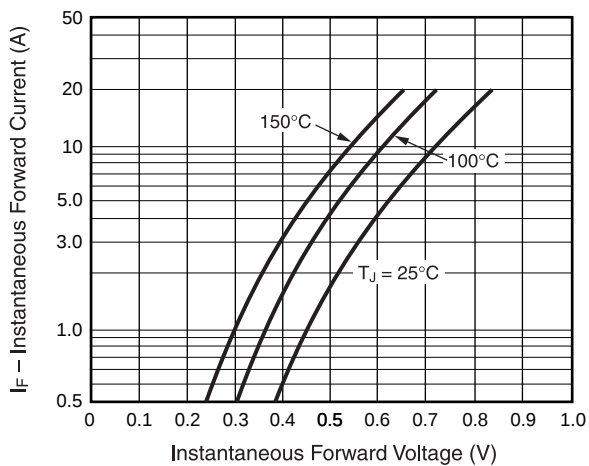


Fig. 4 - Typical Reverse Characteristics

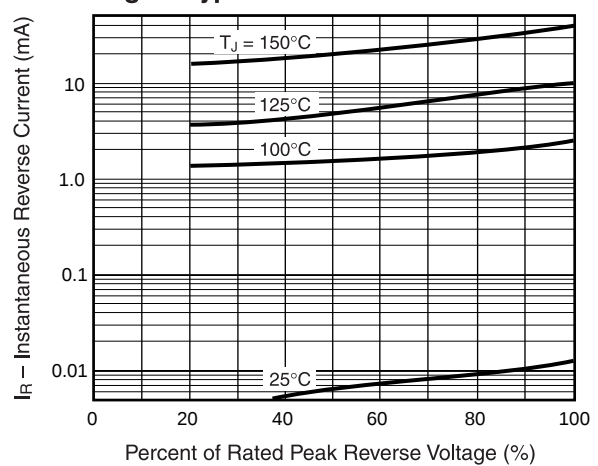


Fig. 5 - Typical Transient Thermal Impedance

